

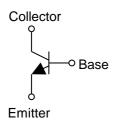
NPN 4.0A 50V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	50V
I _C	4.0A

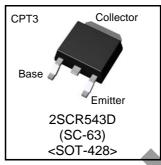
Features

- 1) Suitable for Middle Power Driver
- 2) Complementary PNP Types: 2SAR543D
- 3) Low $V_{CE(sat)}$ $V_{CE(sat)}$ =0.35V(Max.) $(I_C/I_B$ =2A/100mA)
- 4) Lead Free/RoHS Compliant.

•Inner circuit



●Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SCR543D	CPT3	6595	ŤL	330	16	2,500	CR543

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage	oltage V _{EBO}		6	V
Collector current	DC	I _C	4.0	А
	Pulsed	I _{CP} *1	8.0	А
Power dissipation		P_{D}^{*2}	1	W
		P _D *3	10	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C
	*		*	

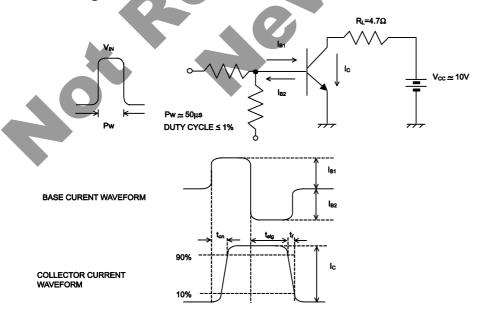
- *1 Pw=10ms, single pulse
- *2 Mounted on a substrate
- *3 Tc=25°C

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 100μA	50	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 100μA	6	ı		V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	ı	-	9	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	-	-	1	μА
Collector-emitter saturation voltage	V _{CE(sat)} *1	$I_C = 2A, I_B = 100mA$		0.13	0.35	V
DC current gain	h _{FE}	$V_{CE} = 3V, I_{C} = 100mA$	180	-	450	-
Transition frequency	f _T	$V_{CE} = 10V, I_{E} = -500 \text{mA}$ f=100MH _Z	-	300	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$	-	20	-	pF
Turn-on time	t _{on} *2	I _C =2A	Ĵ	50	ı	ns
Storage time	t _{stg} *2	I _{B1} =200mA I _{B2} = -200mA	-	450	-	ns
Fall time	t _f *2	V _{CC} ≃10V	-	85	-	ns

^{*1} Pulsed

•Switching time test circuit



^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

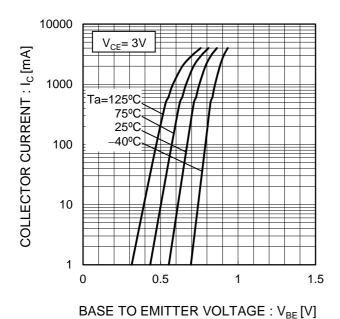
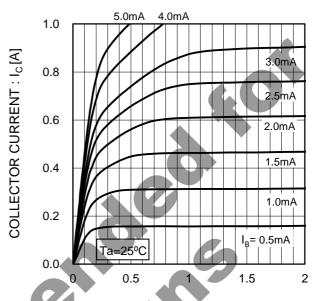


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current(I)

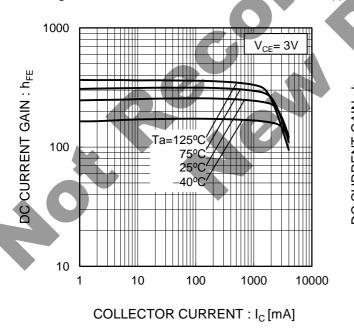
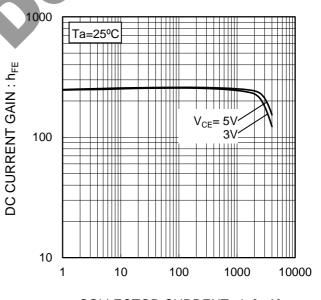
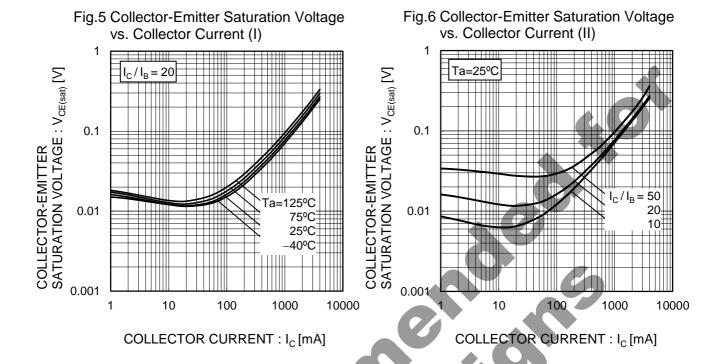


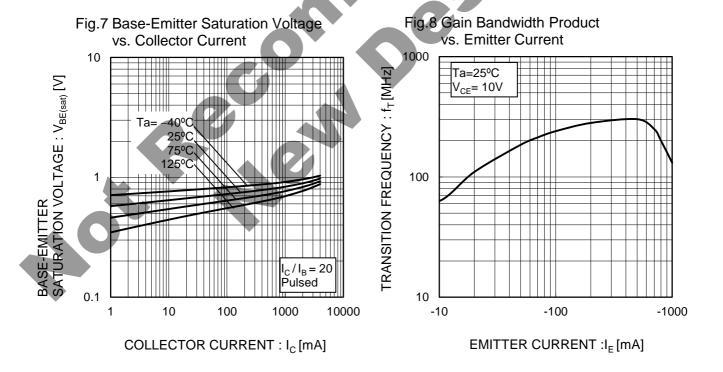
Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [mA]

●Electrical characteristic curves(Ta = 25°C)





●Electrical characteristic curves(Ta = 25°C)

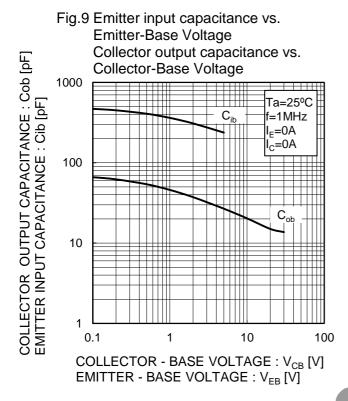
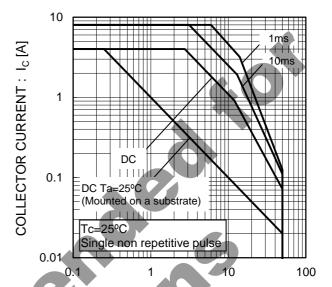
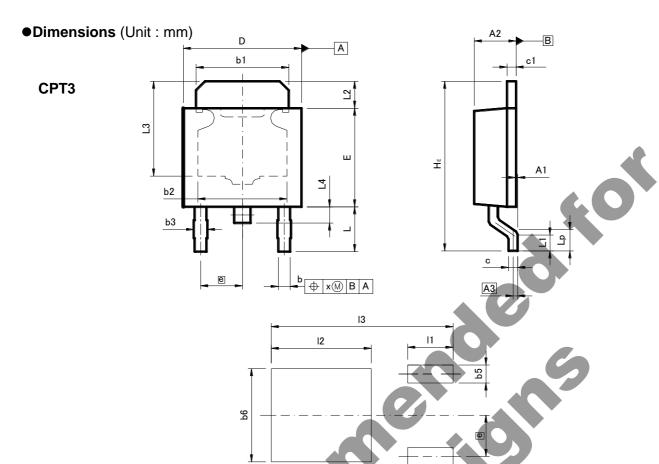


Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]





DIM MILIMETERS		ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.:	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.		0.1	97	
b3	0.	75	0.030		
C	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
e	2.3	30	0.091		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.3	30	0.209		
L4	0.90		0.035		
Lp	1.00	1.60	0.039	0.063	
Х	_	0.25	_	0.010	

Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b5	_	1.00	_	0.04	
b6	1	5.20	ı	0.205	
	-	2.50	-	0.098	
12	_	5.50	_	0.217	
13	-	10.00	-	0.394	

Dimension in mm / inches

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